



# **Strobe High-Current Switching Applications**

An ON Semiconductor Company

## **Applications**

· Strobe, voltage regulators, relay drivers, lamp drivers.

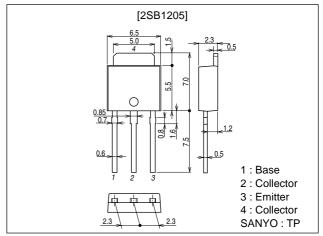
#### **Features**

- · Adoption of FBET, MBIT processes.
- · Low saturation voltage.
- · Fast switching speed.
- · Large current capacity.
- · Small and slim package making it easy to make 2SB1205-applied sets smaller.

## **Package Dimensions**

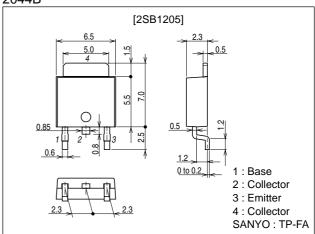
unit:mm

2045B



unit:mm

#### 2044B



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# **Specifications**

## **Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		-25	V
Collector-to-Emitter Voltage	VCEO		-20	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		-5	V
Collector Current	lС		-5	Α
Collector Current (Pulse)	I <sub>CP</sub>		-8	Α
Base Current	IB		-0.5	Α
Collector Dissipation	PC		1	W
		Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

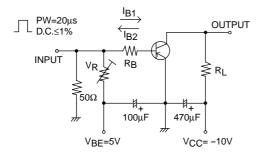
### **Electrical Characteristics** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
Parameter	Symbol	Conditions		typ	max	Unit
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =-20V, I <sub>E</sub> =0			-500	nA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =-4V, I <sub>C</sub> =0			-500	nA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =-2V, I <sub>C</sub> =500mA			400*	
DC Current Gain	h <sub>FE</sub> 2	V <sub>CE</sub> =-2V, I <sub>C</sub> =-4A	60			
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> =-200mA		320		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CE</sub> =-10V, f=1MHz		60		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-3A, I <sub>B</sub> =-60mA		-250	-500	mV
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =-3A, I <sub>B</sub> =-60mA		-1.0	-1.3	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =-10μA, I <sub>E</sub> =0	-25			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =-1mA, R <sub>BE</sub> =∞	-20			V
Emitter-to-Base Breakdown Voltage	V(BE)EBO	I <sub>E</sub> =-10μA, I <sub>C</sub> =0	-5			V
Turn-ON Time	ton	See specified Test Circuit		40		ns
Storage Time	t <sub>stg</sub>	See specified Test Circuit		200		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		10		ns

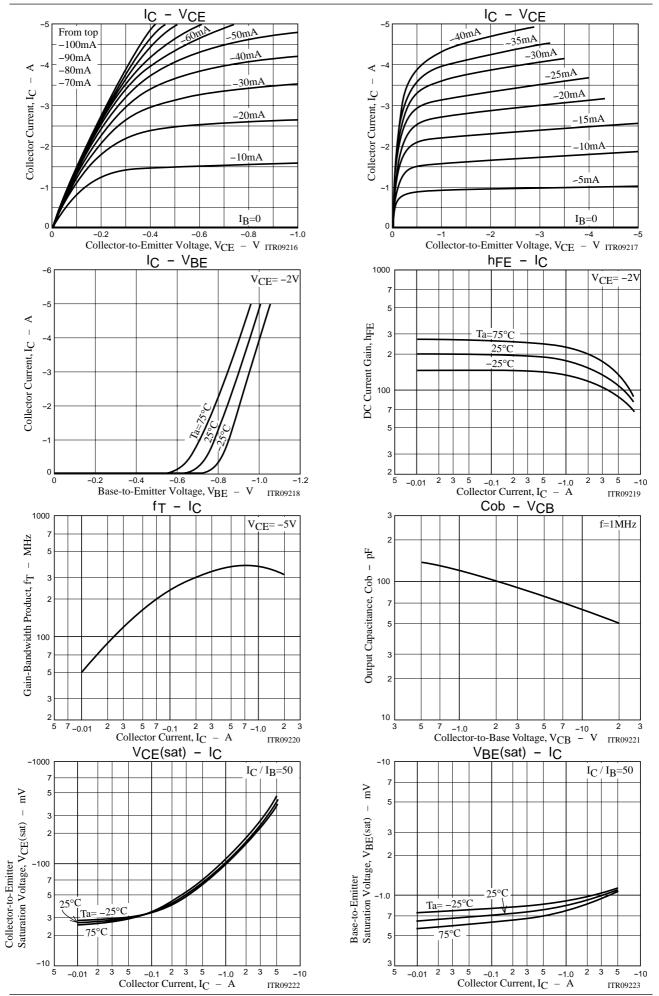
<sup>\* :</sup> The 2SB1205 is classified by 500mA  $h_{_{\rm FE}}$  as follows :

Rank	R	S	Т	
hFE	100 to 200	140 to 280	200 to 400	

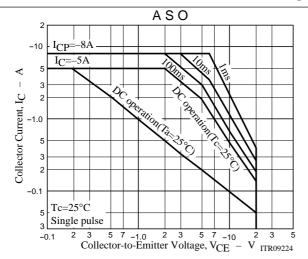
# **Switching Time Test Circuit**

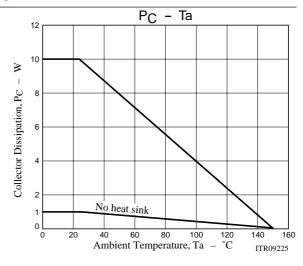


 $I_{C} = -10I_{B1} = 10I_{B2} = -2A$ 



### 2SB1205





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